

View Online at <https://aerobasegroup.com/nsn/5961-01-087-7225>

Inclosure Material:

Metal all transistor

Overall Length:

1.563 inches all transistor

Overall Height:

1.050 inches all transistor

Mounting Facility Quantity:

2 all transistor

Internal Configuration:

Junction contact-darlington connected all transistor

Electrode Internally-electrically Connected To Case:

Collector all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

4 transistor

Mounting Method:

Unthreaded hole all transistor

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

650.0 collector to base voltage, dc all transistor and 400.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, dc all transistor

Current Rating Per Characteristic:

10.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector preset all transistor

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction all transistor

Terminal Type And Quantity:

1 case all transistor and 2 pin all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0